

IMAGING THE MULTI-TEMPORAL DYNAMICS OF PHOTOCARRIERS AT THE NANOMETER SCALE

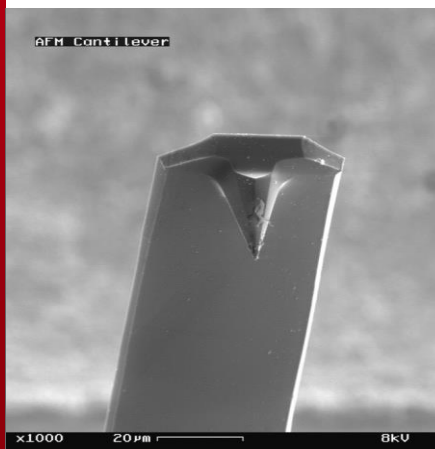
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² CEA, LETI, MINATEC Campus, F-38054 Grenoble, France.

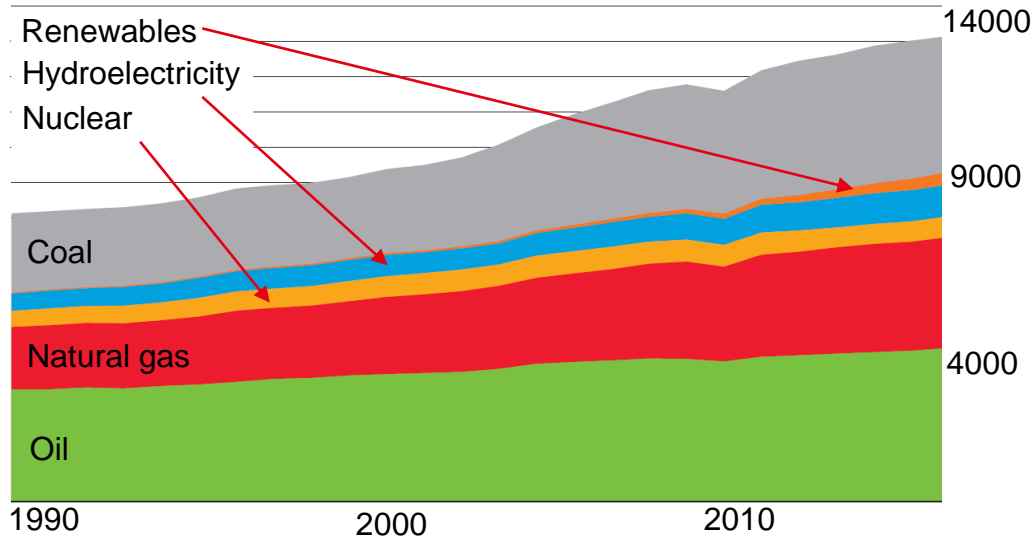
³ CEA, CNRS, INAC-SPrAM, F-38054 Grenoble, France.

leti



World energy consumption Million tonnes oil equivalent

Source: BP Statistical Review of World Energy June 2016

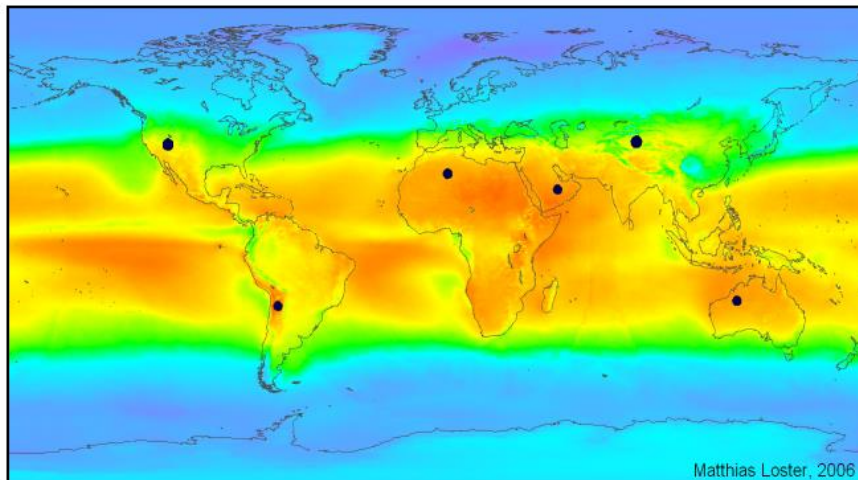


Since 1992
worldwide PV
capacity
doubled up
each 2.4 years

Source: Statistical Review of World Energy – Historical Data Workbook BP

Worldwide PV
capacity grew
by 32% last
year only

Source:
www.solarpowereurope.org/insights/new-global-market-outlook-2016/



$\Sigma \bullet = 18 \text{ TWe}$

Average Insolation

Black dots represents the theoretical area sufficient to supply the world's total energy needs of 18 TW with solar power

Source: Matthias Loster, 2010 http://www.ez2c.de/ml/solar_land_area/

PHYSICAL KEY PARAMETERS

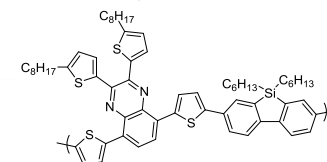
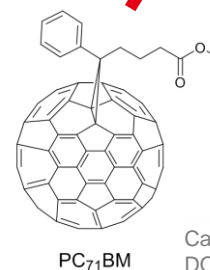
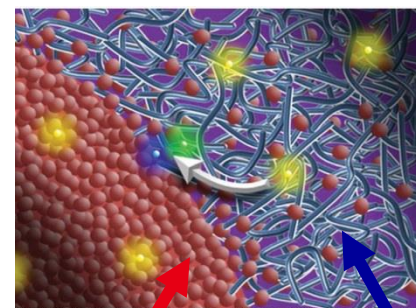
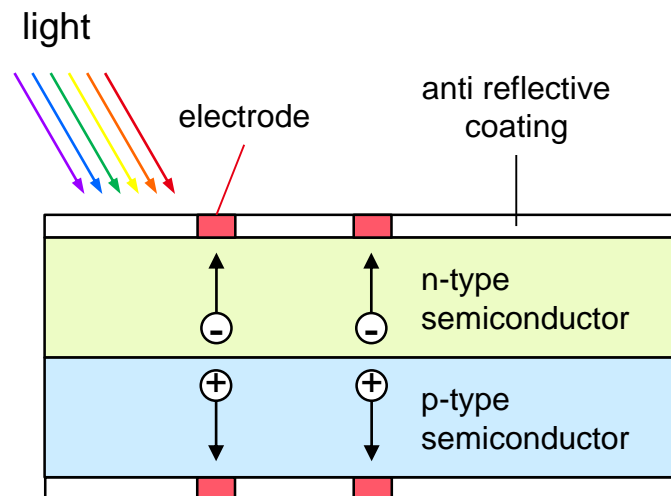
- Carrier mobility μ
- **Photo-carrier dynamics τ**
- Absorption coefficient α / Gap E_g

WHY τ IS IMPORTANT?

- Limits the collection of photo-generated charges by the electrodes of the solar cell.

PHOTO-CARRIER DYNAMICS AT THE NANOSCALE

- Real characterization need.
- Assess morphology influence on the performance.



Caffy, F. et al. Polym. Chem.
DOI: 10.1039/C6PY00370B
(2016).

TRANSIENT (Pulsed excitation, decay time)	STEADY-STATE (Modulated excitation, averaged signal)
Photo Conductance (PCD, QSSPC)	
Short-Circuit Current (SCCD)/Open-Circuit Voltage (OCVD)	
Free Carrier Absorption	
Photoluminescence (PL)	
	Surface Photo Voltage (SPV)

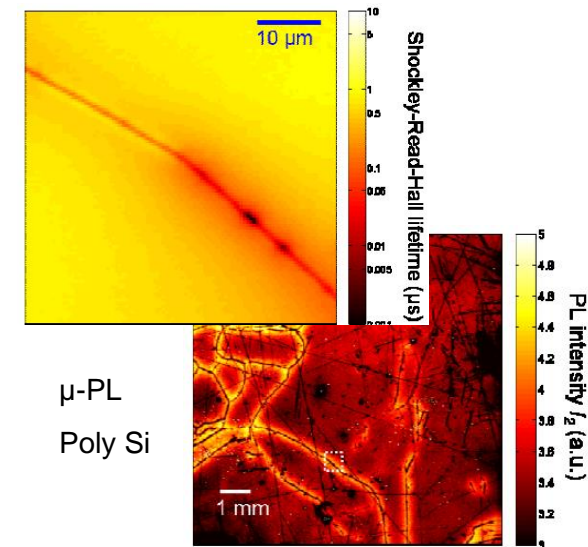
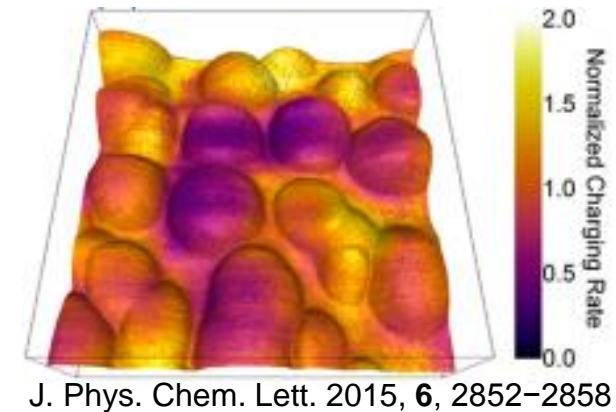
D. K. Schroder, Semiconductor Material and Device Characterization, John Wiley & Sons, (2006)



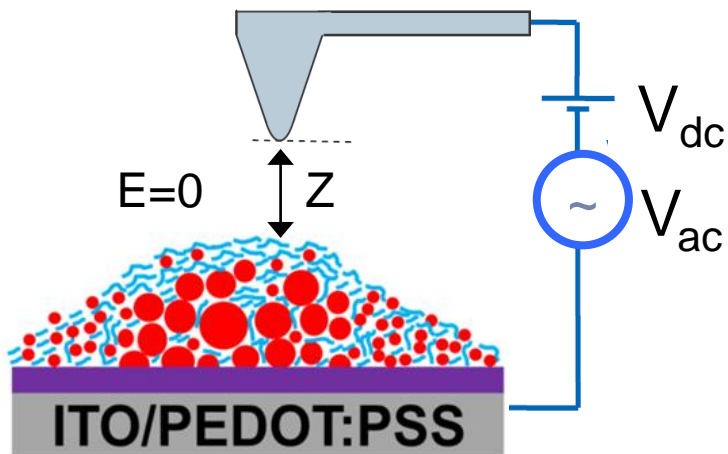
SPECTROSCOPY AND/OR MAPPING AT 10 NM SCALE ?

• Kelvin Probe Force Microscopy

Organic, inorganic and hybrid photovoltaic materials



JAP **108**, 033705 (2010)



$$V_{CPD} = \frac{\Phi_{probe} - \Phi_{sample}}{|e|}$$

M. Nonnenmacher et al., Appl. Phys. Lett. 58, 25 (1991)
Ł. Borowik et al. Phys. Rev. B 82, 073302 (2010)

Feedback loop to cancel force /force gradient $V_{DC} = \pm V_{CPD}$

Force mode

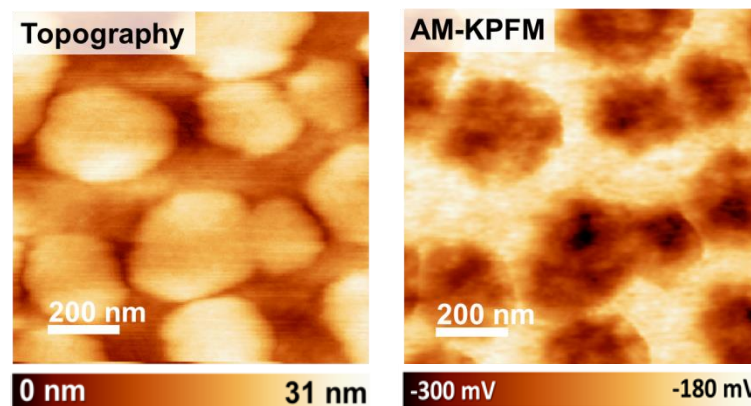
$$F_{\omega_{elec}} = \frac{\partial C}{\partial z} \sin(\omega t) (V_{DC} - V_{CPD}) V_{AC}$$

Amplitude modulation (AM-KFM)

Force Gradient mode

$$\frac{\partial F_{\omega_{elec}}}{\partial z} = \frac{\partial^2 C}{\partial z^2} (V_{DC} - V_{CPD}) \times V_{AC} \sin(\omega t)$$

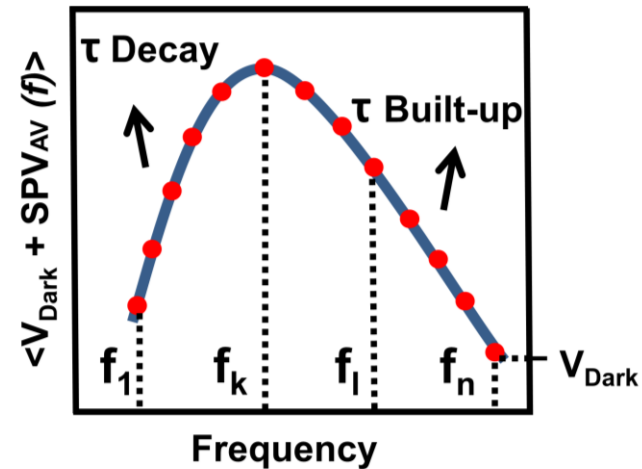
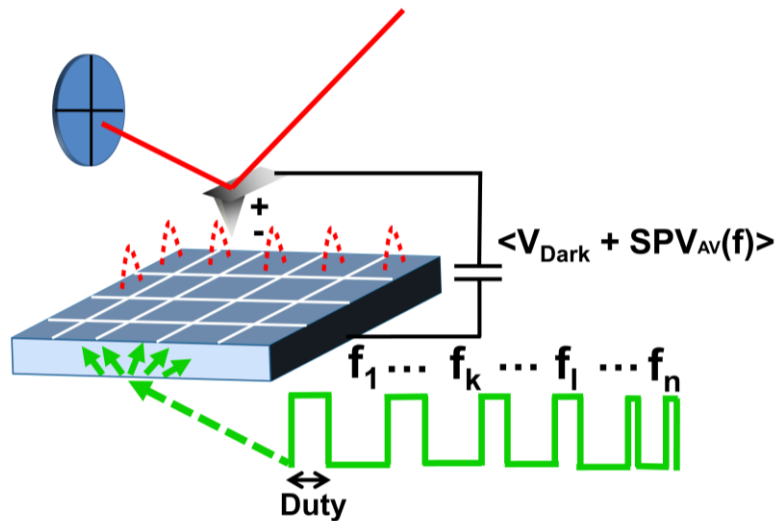
Frequency modulation (FM-KFM)



Resolution

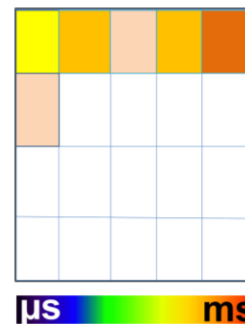
Potential < 5 mV

Spatial 5-50 nm

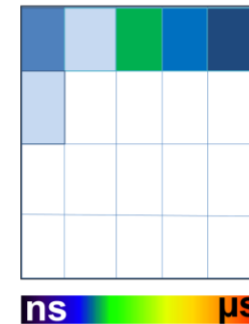


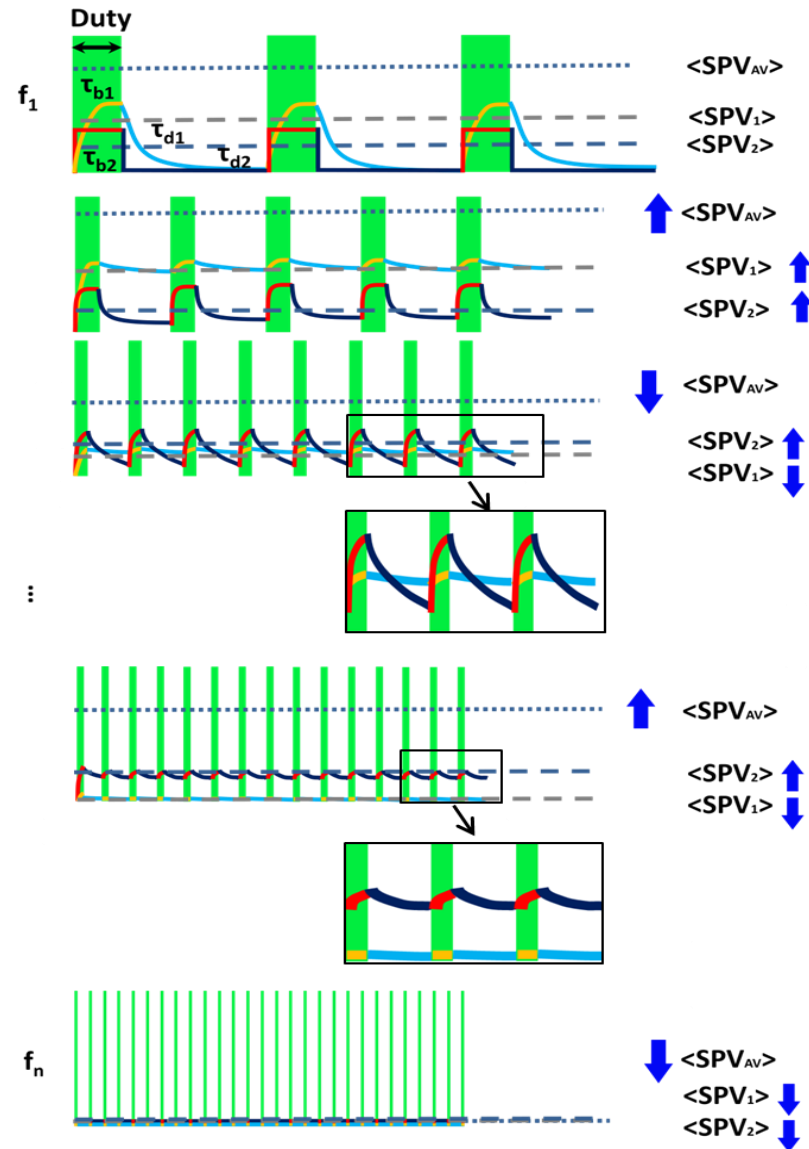
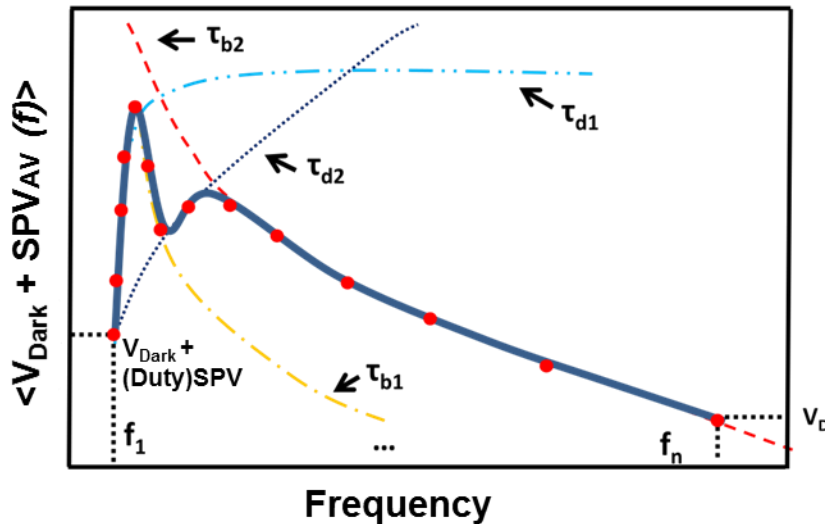
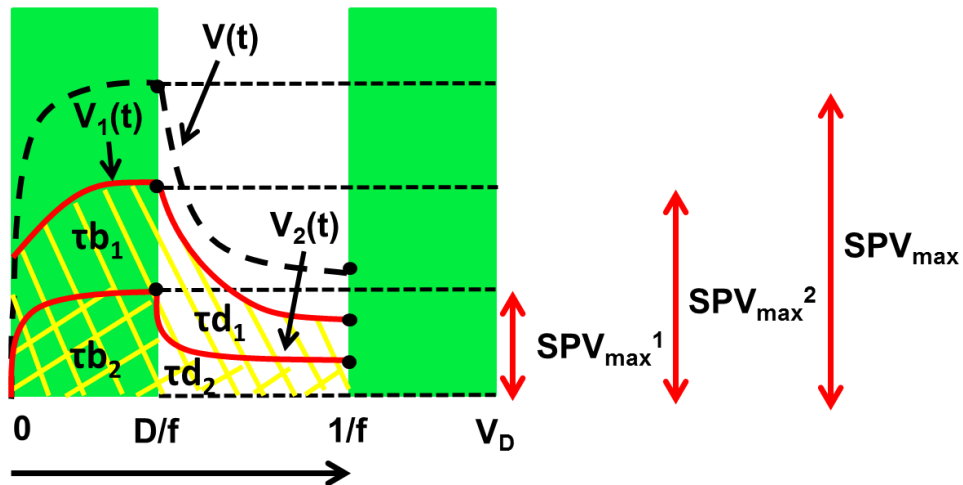
A curve fit is performed on each pixel to recalculate 2D images of the time-constants.

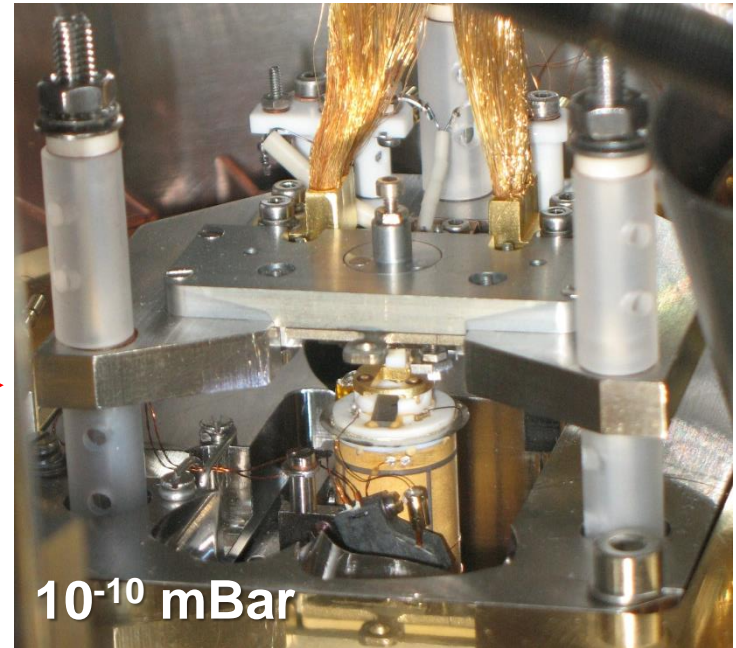
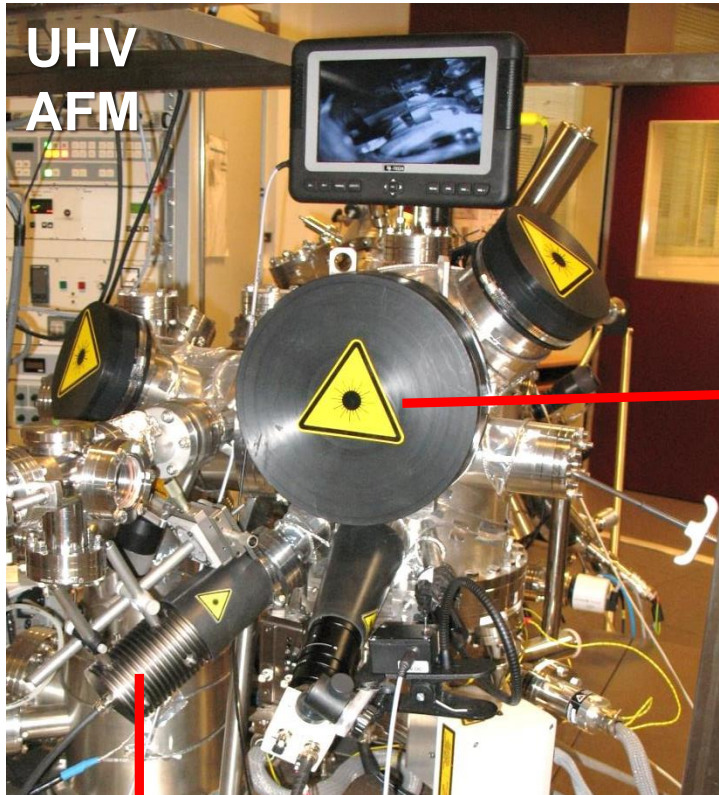
τ Decay image



τ Built-up image







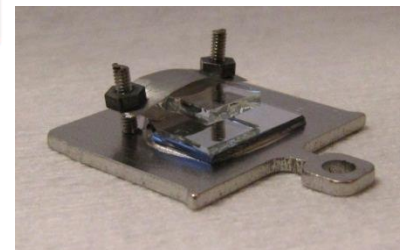
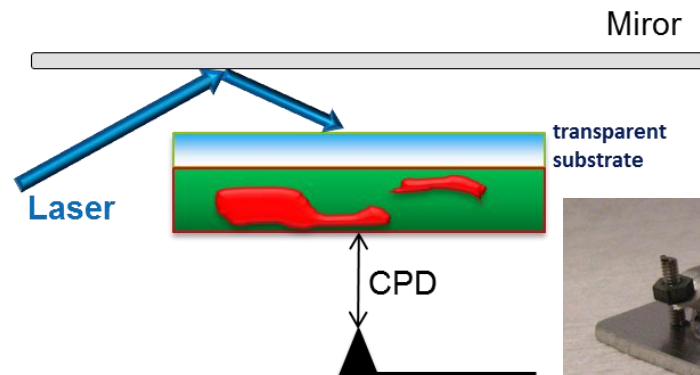
Omicron UHV-AFM VT XA

EXTERNAL ILLUMINATION

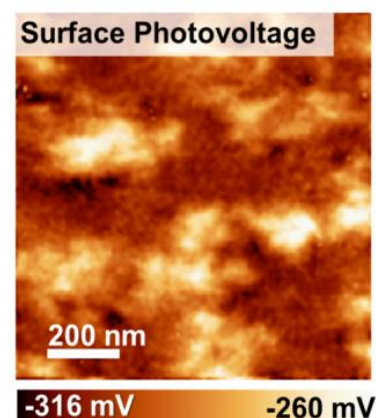
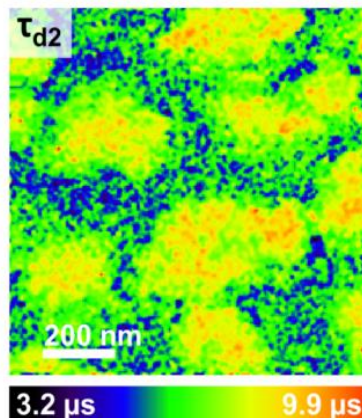
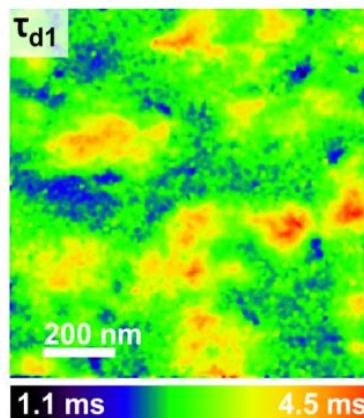
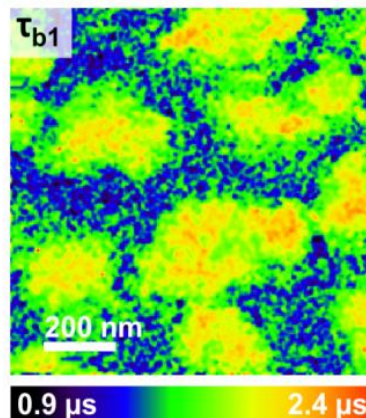
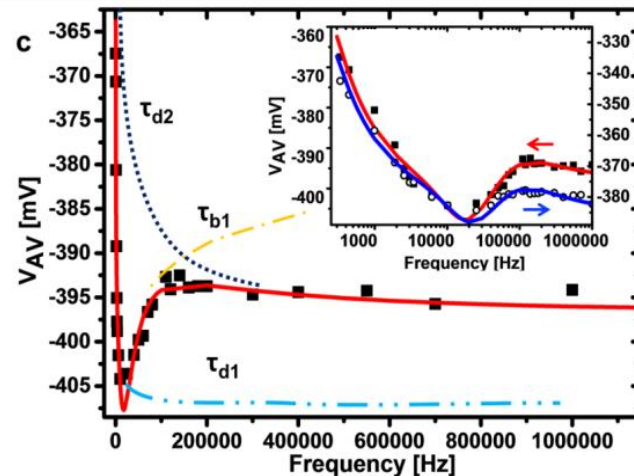
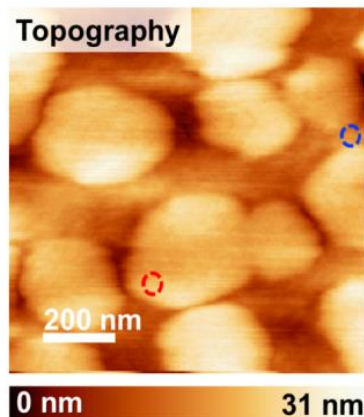
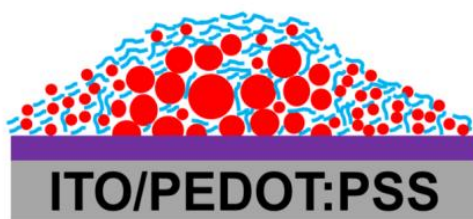
Red, green and blue lasers

DC to 10 MHz

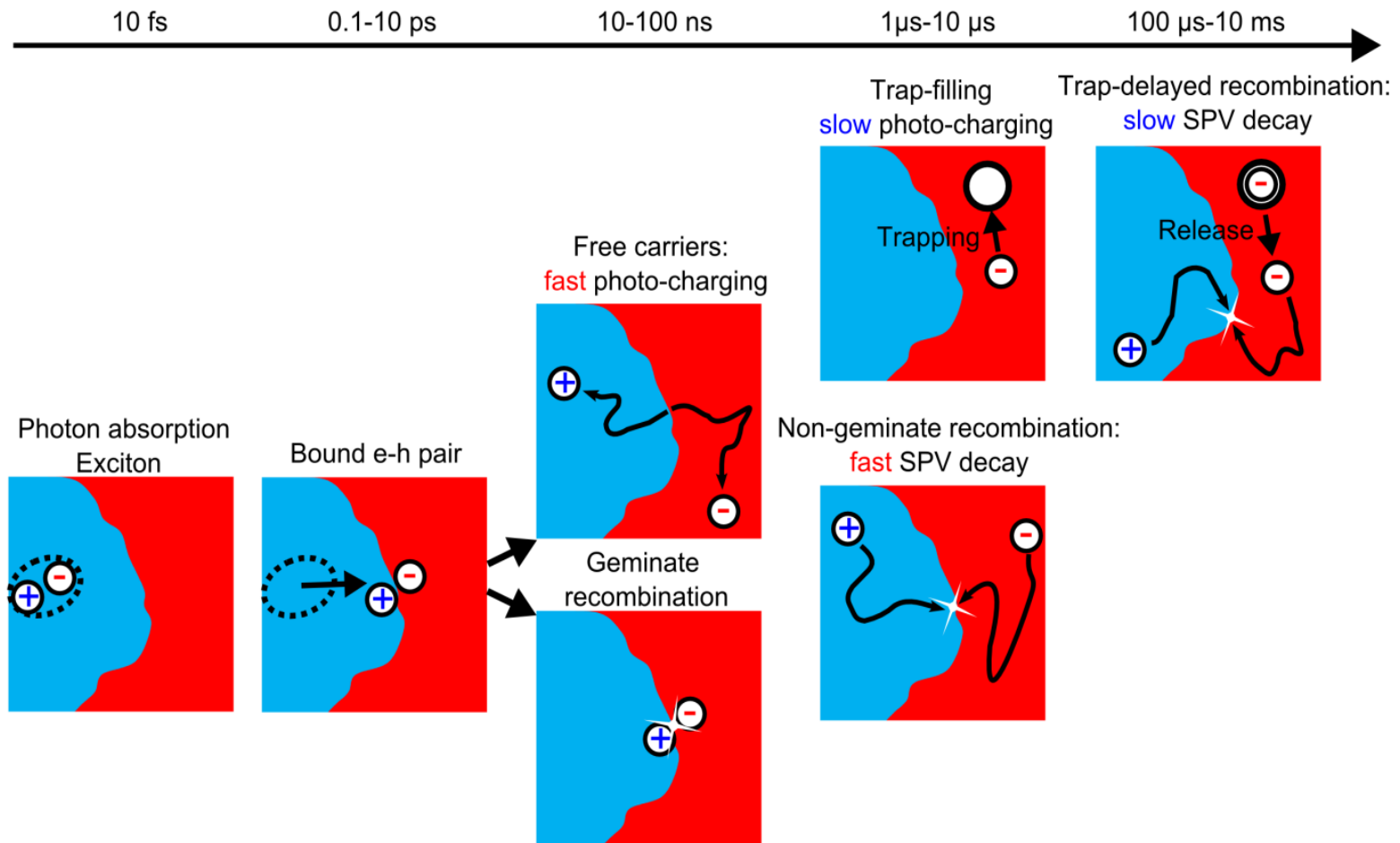
Power 0.2 to 80 mW

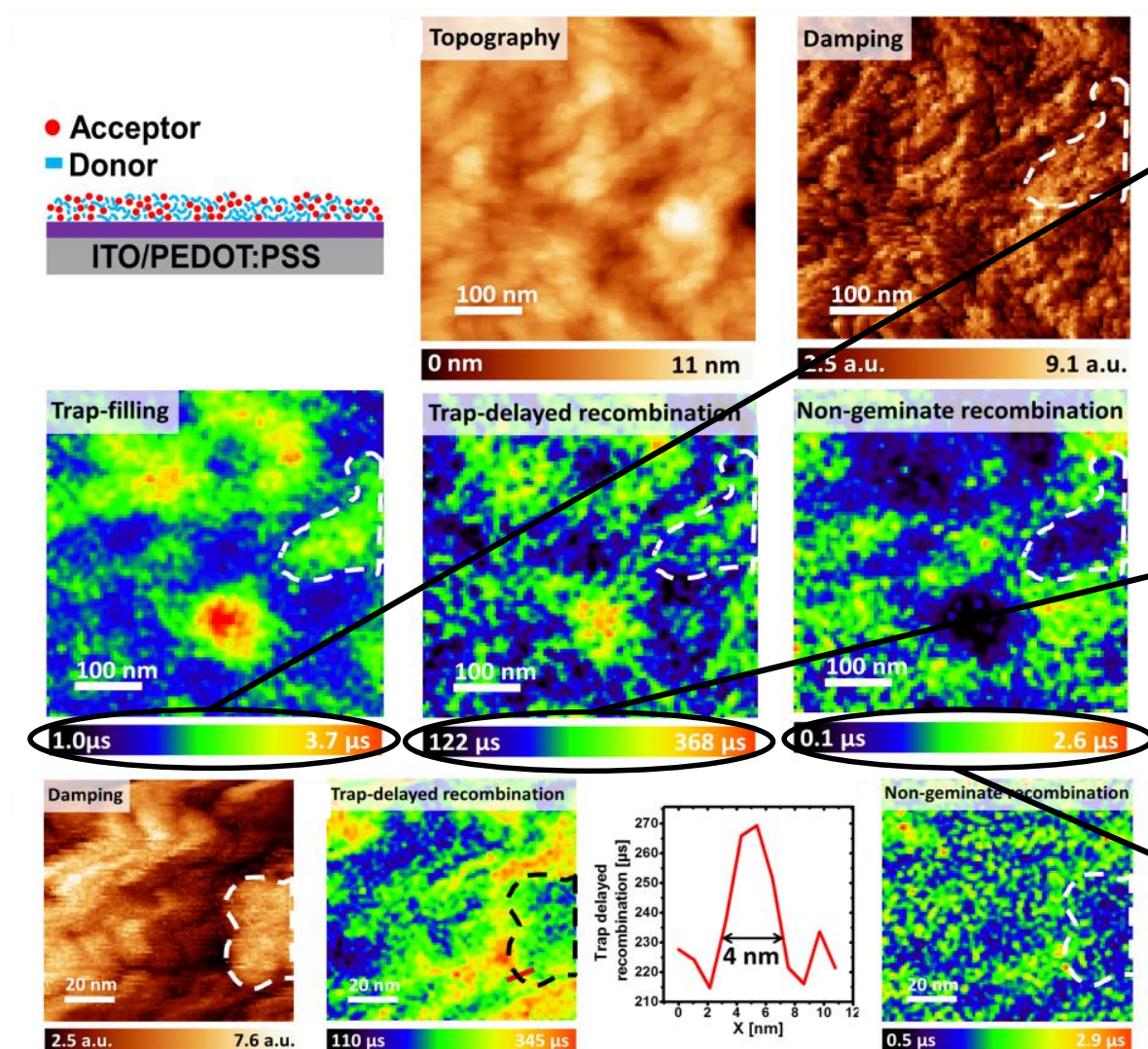


● Acceptor
■ Donor



PHOTOCARRIERS DYNAMICS STRONGLY INFLUENCED BY SAMPLE'S MORPHOLOGY !





McNeill, C.; Hwang, I.; Greenham, N. Photocurrent Transients in All-Polymer Solar Cells: Trapping And Detrapping Effects. *J. Appl. Phys.* **2009**, 106, 024507.

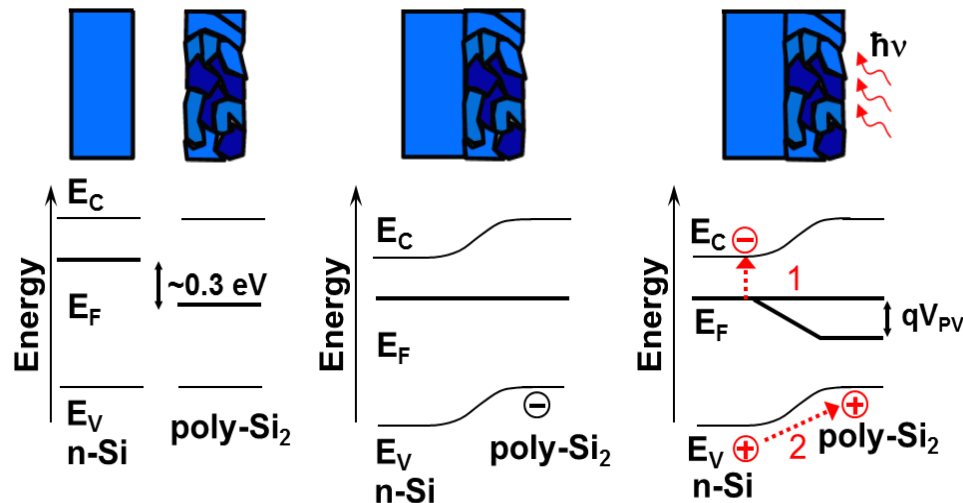
Shuttle, C.; Treat, N.; Douglas, J.; Fréchet, J.; Chabinc, M. Deep Energetic Trap States in Organic Photovoltaic Devices. *Adv. Energy Mater.* **2012**, 2, 111-119.

Elliott, L.; Basham, J.; Pernstich, K.; Shrestha, P.; Richter, L.; DeLongchamp, D.; Gundlach, D. Probing Charge Recombination Dynamics in Organic Photovoltaic Devices Under Open-Circuit Conditions. *Adv. Energy Mater.* **2014**, 4, 1400356.

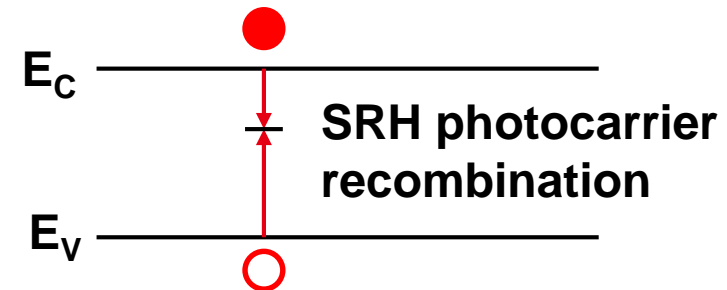
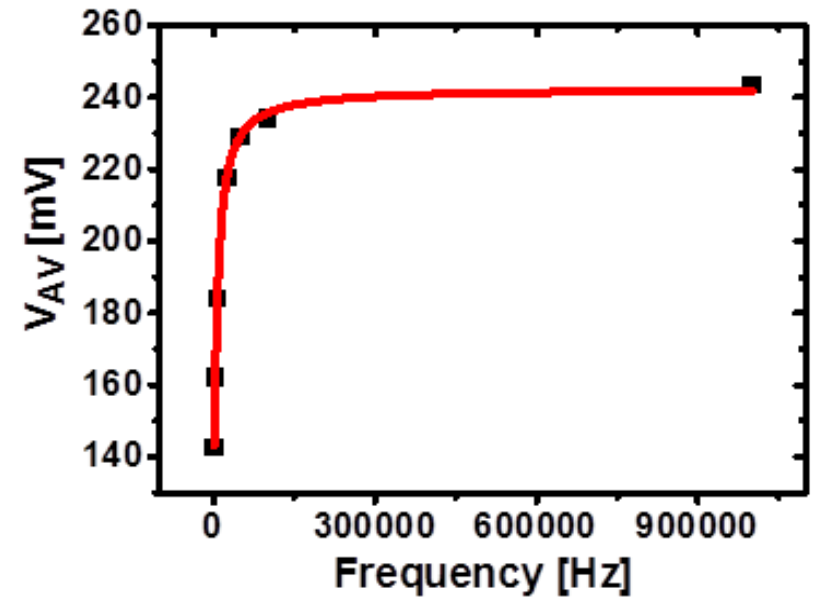
Poly Si

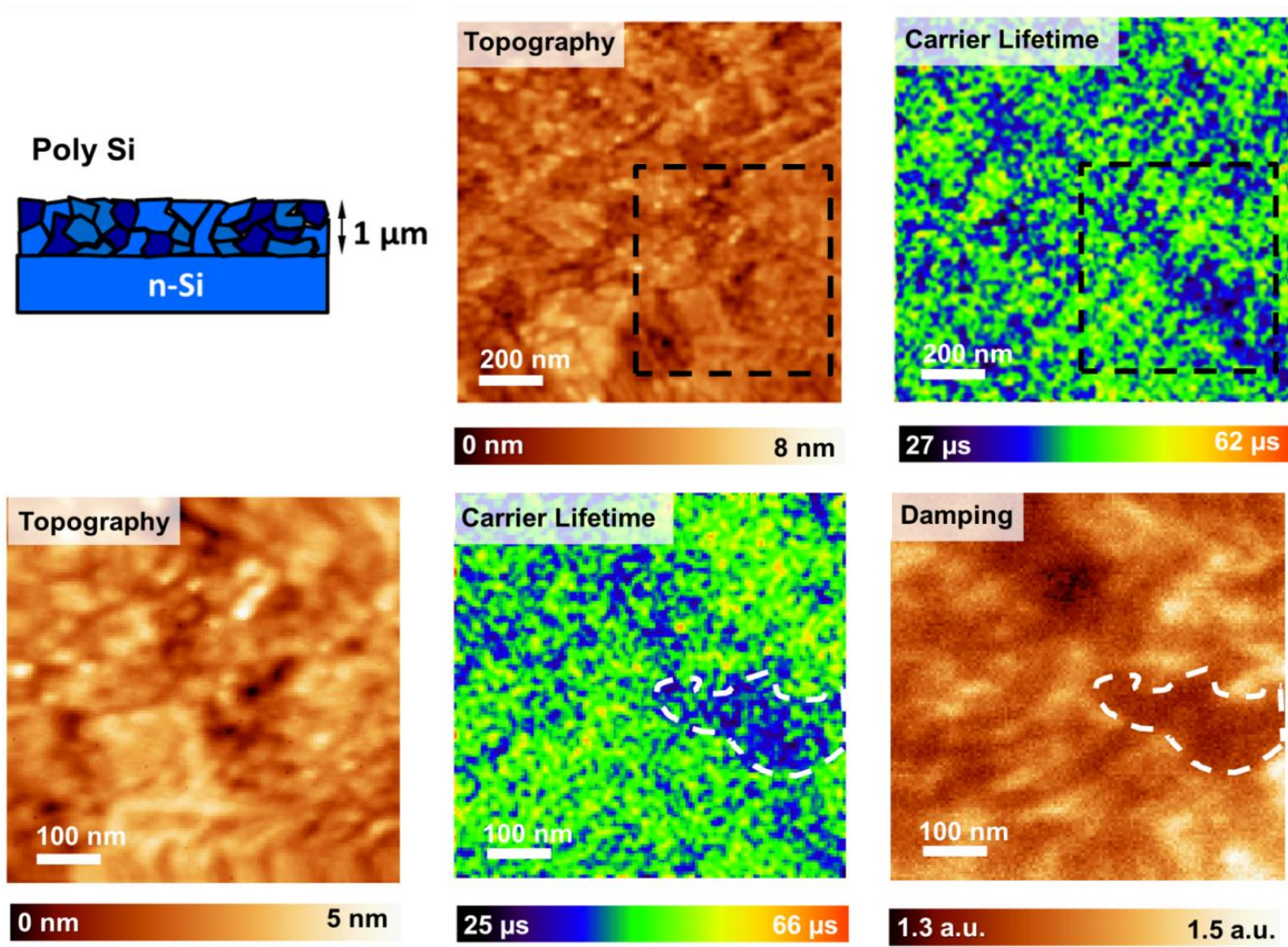


Doping level 10^{15} cm^{-3}



$$V_{av} = V_D + SPV_{max} D + SPV_{max} f\tau_d \left(1 - e^{-\frac{(1-D)}{f\tau_d}}\right)$$





MEASUREMENTS ARE SENSITIVE TO SURFACE STATES !

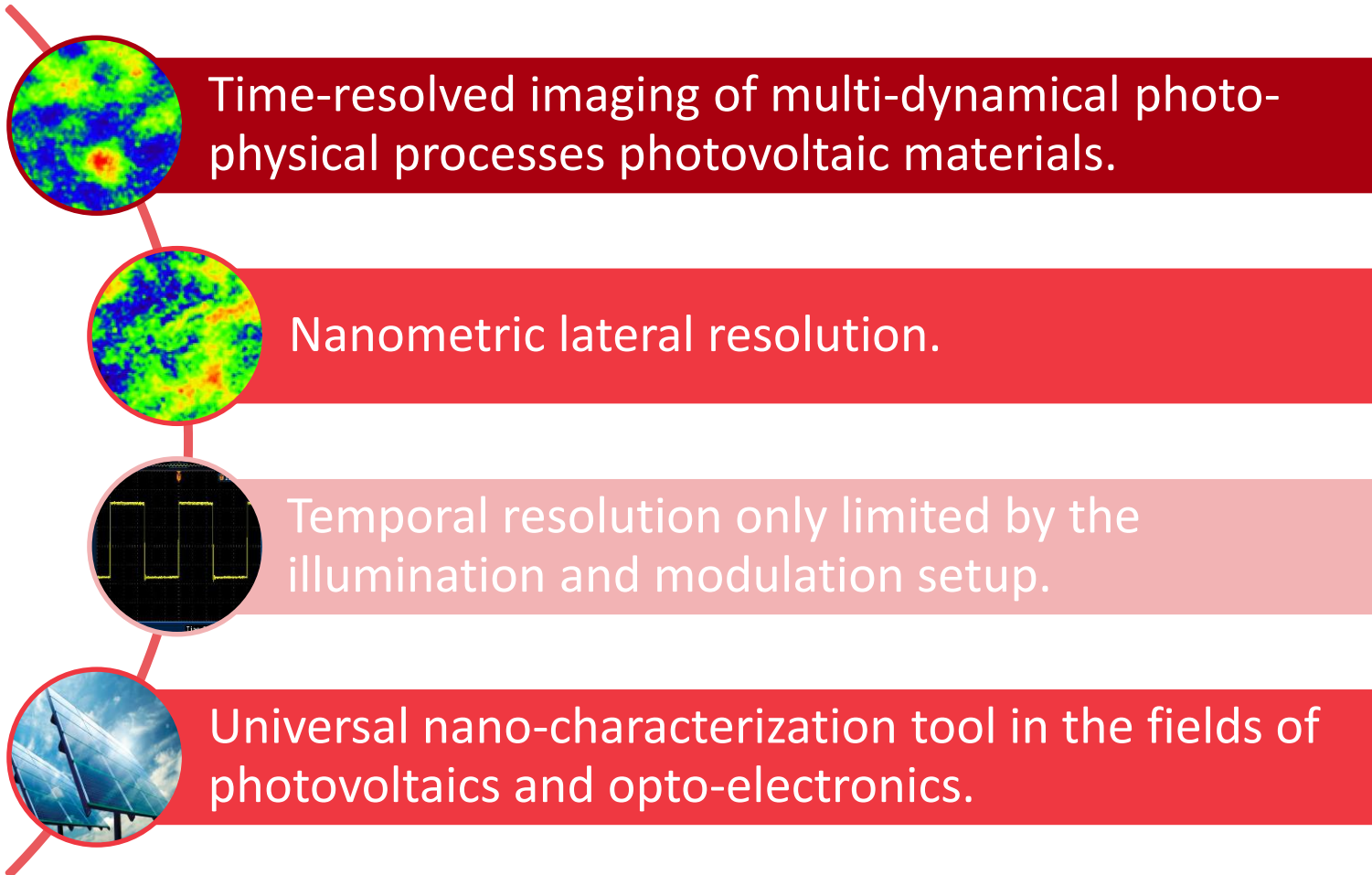
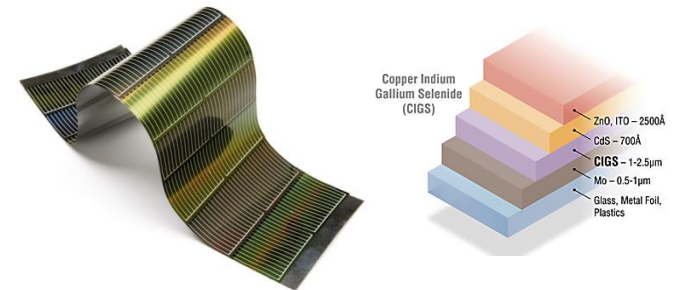


Photo-carrier dynamics of several categories of D-A blends

Investigation of Poly-Si after surface passivation

Implementation in ambient conditions

Comparative analysis with macroscopic measurements



Thank you for
your attention!